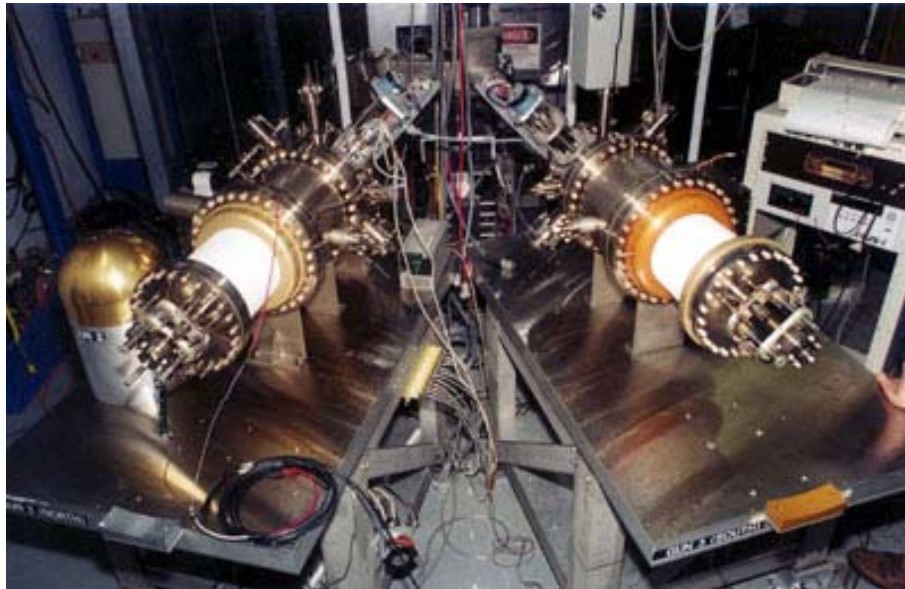


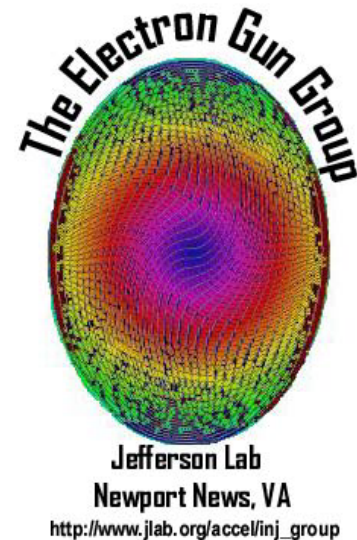
Polarized Source

status report

Maud Baylac



aka The EGG



Hall A Parity Meeting
Jefferson Lab
May 10, 2002



Thomas Jefferson National Accelerator Facility

Polarized injector guns

- 2 identical horizontal guns installed in 1998
- Gun 2 in use Oct 2000 – Jan 2001, then suffered field emission
- Gun 3 in use Feb 2001 – Mar 2002
- **Since April shutdown, 2 working guns**
- Each gun equipped with

high polarization photocathode



A few numbers

- **QE**

0.2% at 840 nm \Rightarrow I (uA) \sim P (mW)

1 % at 770 nm \Rightarrow I (uA) \sim 6 P (mW)

- **Polarization**

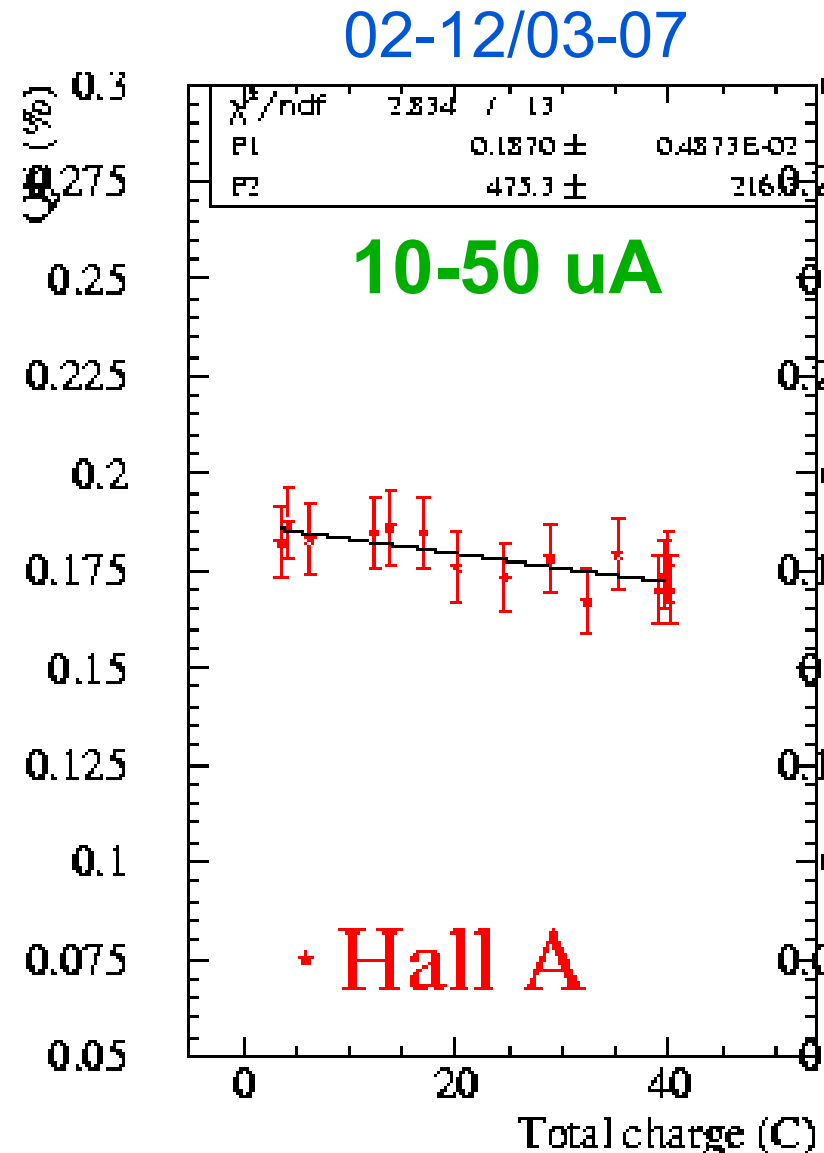
70 to 80 % at cathode

measured by Mott, Moller, Compton



Lifetime (1/e)

- **Low current : lifetime ~ 600 C**
beam to 3 halls for 3 months
with one single activation
- **High current : lifetime ~ 300 C**
uninterrupted beam for 3 weeks
- **One year with only 3 activations!**



Lasers

- **Perfect Laser** : 5 W DC diode laser => DC electron beam chopped to get RF structure
 - simple : one single beam, no laser phase
 - light with large emitting aperture => new gun
- Next best thing : 3 lasers, 3 HC adjustment knobs
- **Diode** :
 - easy, low maintenance, reliable
 - low noise $\sim 0.1\%$ @ 30 Hz
 - low power < 100 mW
 - DC light => leakage
 - Original vendor SDL quit selling amps



Lasers (cont.)

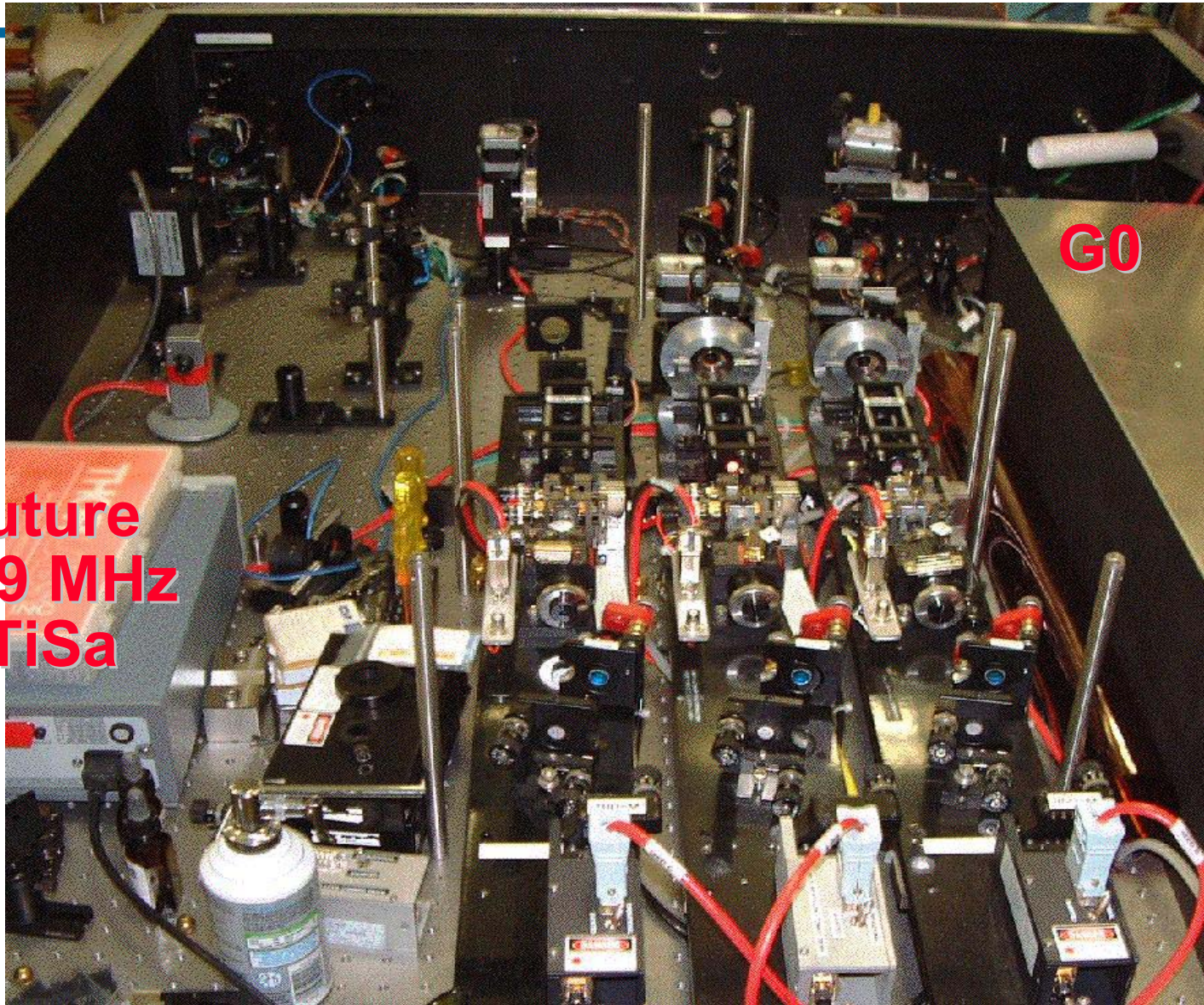
- **TiSa:**
 - high power ~ 300 mW
 - wavelength adjustable
 - high maintenance
 - noisy ~ 1% @ 30 Hz
- Immediate future solution :
 - diode** : low current polarized, high current unpolarized
 - commercial TiSa** for high current and high Pe
 - vendor claims diode-like specs
 - G0 : delivered in July
 - or improve our homebuilt TiSa



Present setup

future
499 MHz
TiSa

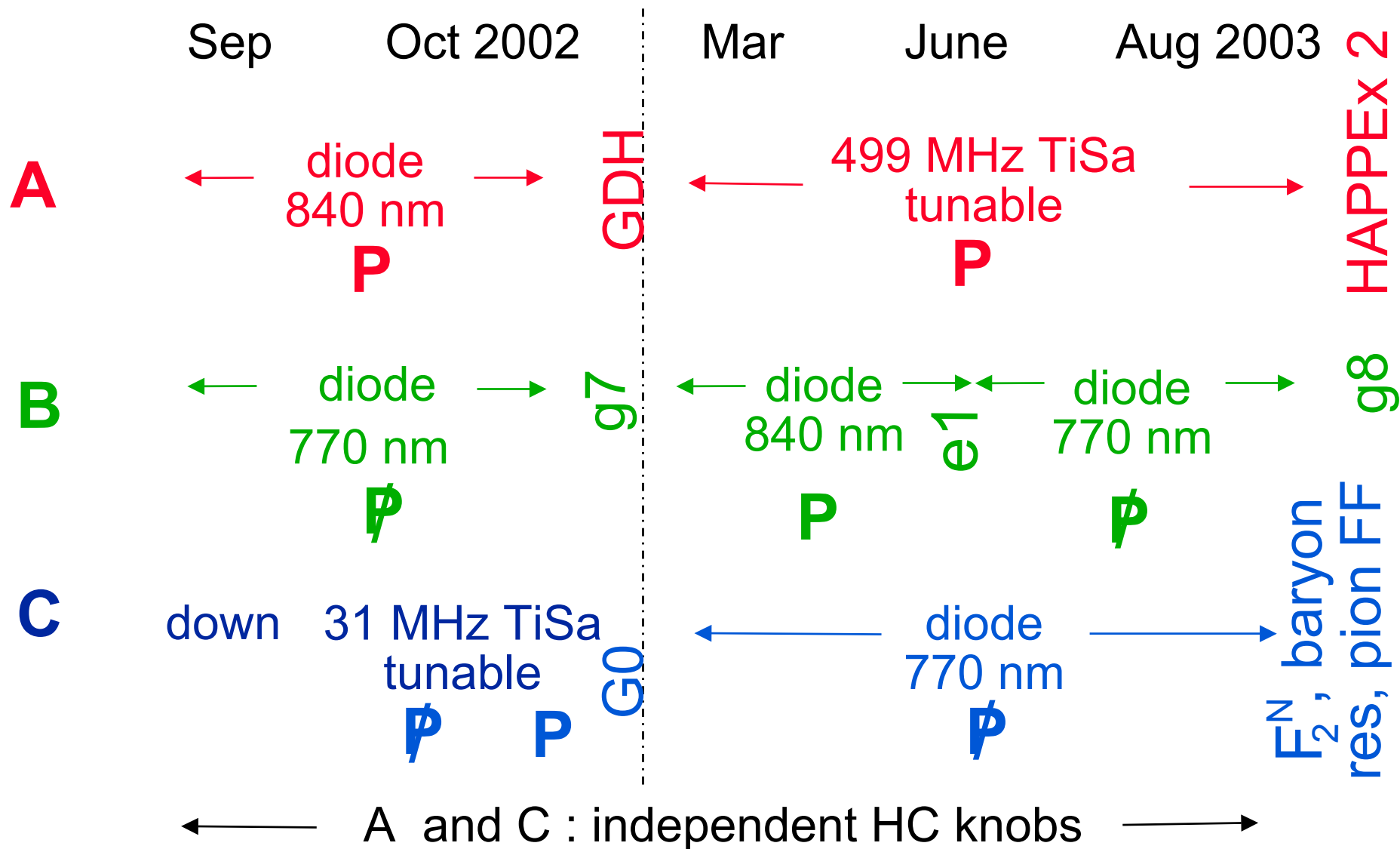
G0



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Future timeline



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Photocathode research

QE, Pe : always higher

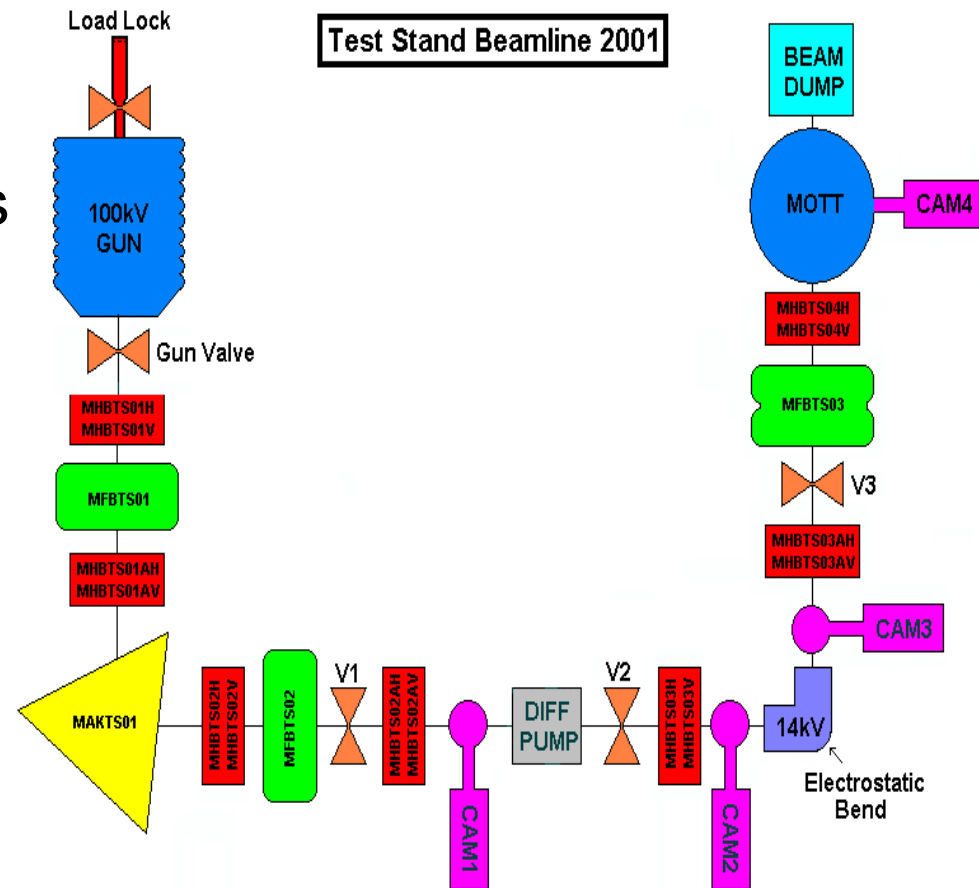
- Study of best chemicals for activation
- Evaluation of new samples
- Study of polarization versus Hydrogen exposure



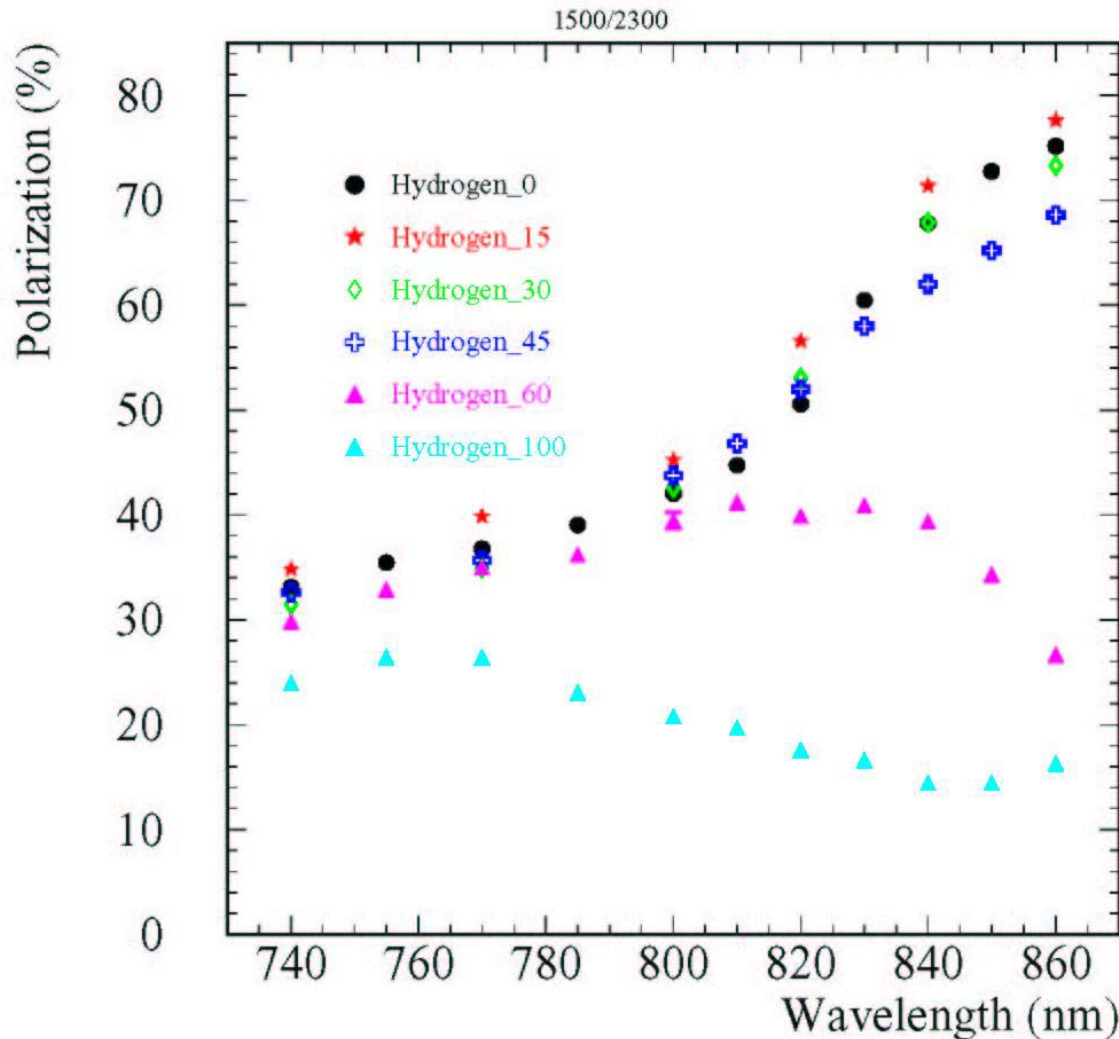
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Hydrogen exposure study

- Strained layer GaAs wafer
- Repeat Hydrogen exposures
- Load to VGun
- Activation (Cs + NF₃)
- Run 100 kV beam
- Measurement of
QE
Polarization

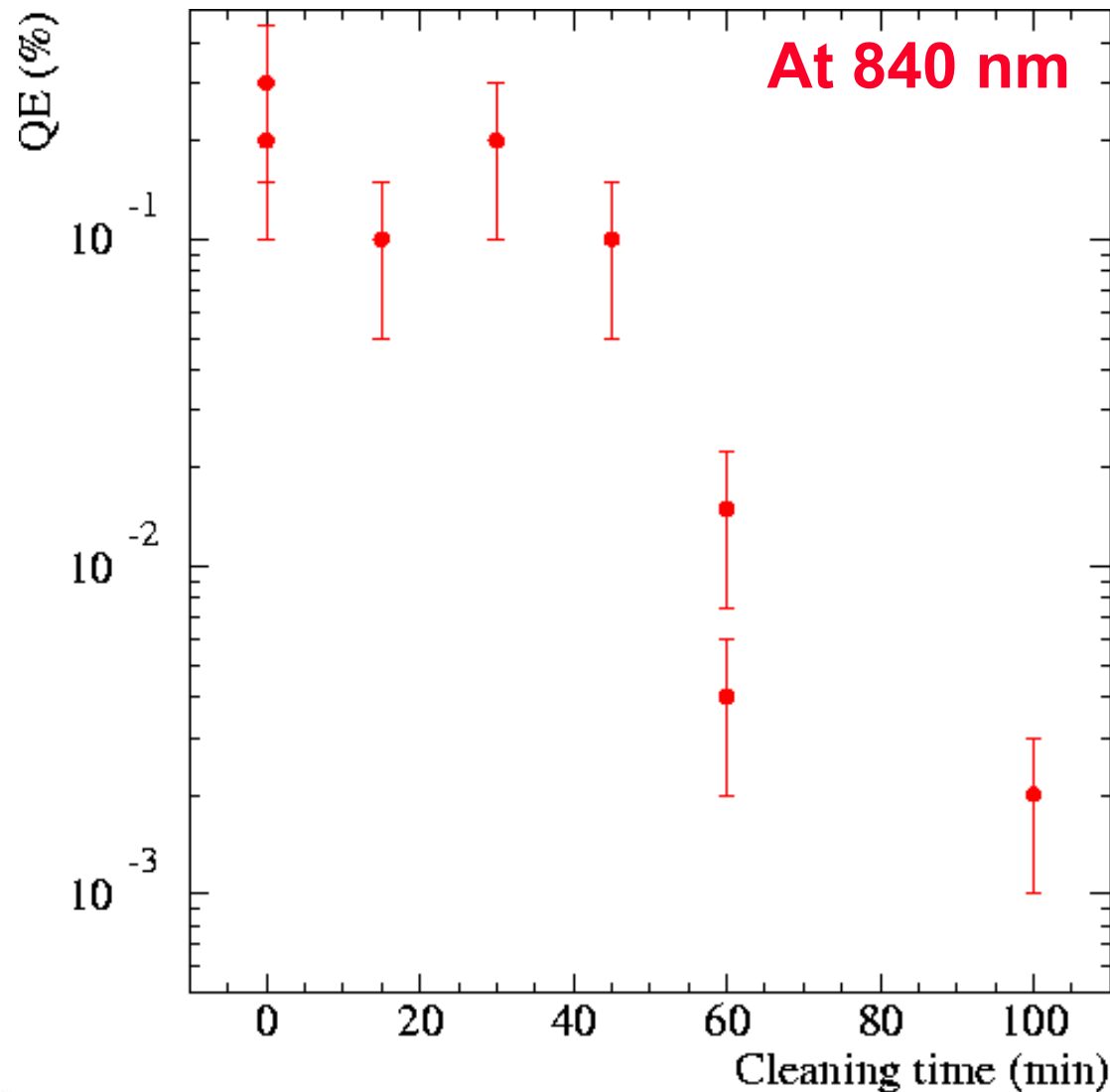


Polarization vs Hydrogen exposure



P max ~ 80%
at 860 nm
with 15 min

QE vs Hydrogen exposure



Real effect,
or procedure?

Polarization vs Hydrogen exposure : preliminary results

- Small dose slightly increases Pe, high dose kills Pe and QE
- This behavior explains old bad results with same material
- Users now get the highest possible Pe
gun 2 wafer, 15 min H -> **Pe ~ 76 % (Mott)**
- Study continues :

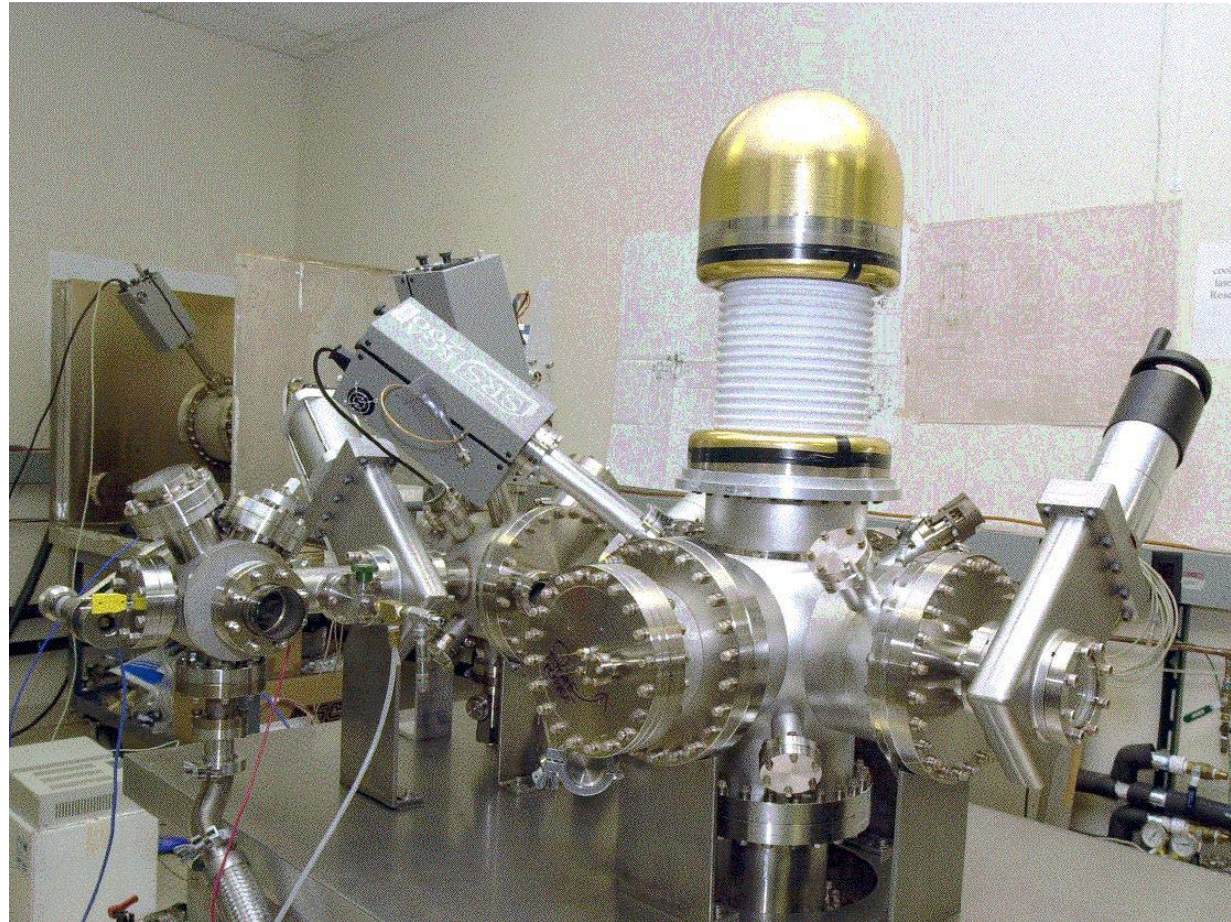
repeat with strained and bulk
check QE behavior in another chamber
improve design : gun, Mott
model effect, better Hydrogen sources?

=> goal : Pe ~ 85 %



Best Technology Load Lock Polarized Electron Gun

- New generation gun
- Entire cathode prep within the gun
- Change to a new wafer within ~ 8 h (vs 3 days now)
- Moved to the test stand in April, commissioning underway



BTLLPEG studies

- Lifetime

few mA to a dump

- Emittance
- Helicity correlations
- Polarimetry
- Timescale ~ 1 year



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Summary

- Excellent results with guns (Pe, lifetime)

- Laser status :

GDH : “easy” diode

G0 / HAPPEX 2 : commercial TiSa to be tested

HC : Joe’s talk

- Rich photocathode research program in the test cave
- Load-locked gun getting commissioned
- Dealing with Charlie’s departure

